

NPN MEDIUM POWER TRANSISTORS IN SOT89

Features

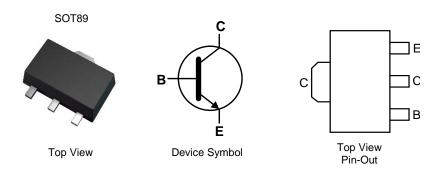
- BV_{CEO} > 45V, 60V & 80V
- I_c = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Gain Groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary PNP Types: BCX51, 52, and 53
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads.
 Solderable per MIL-STD-202 Method 208 (e3)
- Weight: 0.055 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



Ordering Information (Notes 4 & 5)

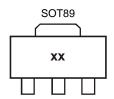
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
BCX54TA	AEC-Q101	BA	7	12	1,000	
BCX5410TA	AEC-Q101	BC	7	12	1,000	
BCX5416TA	AEC-Q101	BD	7	12	1,000	
BCX5416-13R	AEC-Q101	BD	13	12	4,000	
BCX55TA	AEC-Q101	BE	7	12	1,000	
BCX5510TA	AEC-Q101	BG	7	12	1,000	
BCX5516TA	AEC-Q101	BM	7	12	1,000	
BCX56TA	AEC-Q101	BH	7	12	1,000	
BCX5610TA	AEC-Q101	BK	7	12	1,000	
BCX5616TA	AEC-Q101	BL	7	12	1,000	
BCX5616TC	AEC-Q101	BL	13	12	4,000	
BCX5410TC	AEC-Q101	BC	13	12	4,000	
BCX5416TC	AEC-Q101	BD	13	12	4,000	
BCX54TC	AEC-Q101	BA	13	12	4,000	
BCX5510TC	AEC-Q101	BG	13	12	4,000	
BCX5516TC	AEC-Q101	BM	13	12	4,000	
BCX55TC	AEC-Q101	BE	13	12	4,000	
BCX5610TC	AEC-Q101	BK	13	12	4,000	
BCX56TC	AEC-Q101	BH	13	12	4,000	
BCX5616QTA	Automotive	Refer to http://diodes.com/datasheets/BCX5616Q.pdf				

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information



xx = Product Type Marking Code, as follows:

BCX55 = BE BCX56 = BH BCX54 = BABCX5510 = BG BCX5610 = BK BCX5410 = BCBCX5416 = BD BCX5516 = BM BCX5616 = BL

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX54	BCX55	BCX56	Unit
Collector-Base Voltage	V_{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V _{EBO}	6			V
Continuous Collector Current	Ic	1			А
Peak Pulse Collector Current	I _{CM}	2			
Continuous Base Current	I _B	100			A
Peak Pulse Base Current	I _{BM}	200			mA mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 6)		1		
Power Dissipation	(Note 7)	P_D	1.5	W	
	(Note 8)		2.0		
	(Note 6)		125		
Thermal Resistance, Junction to Ambient Air	(Note 7)	$R_{\theta JA}$	83	°C/W	
	(Note 8)		60		
Thermal Resistance, Junction to Lead	(Note 9)	$R_{ heta JL}$	13	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-65 to +150	°C		

ESD Ratings (Note 10)

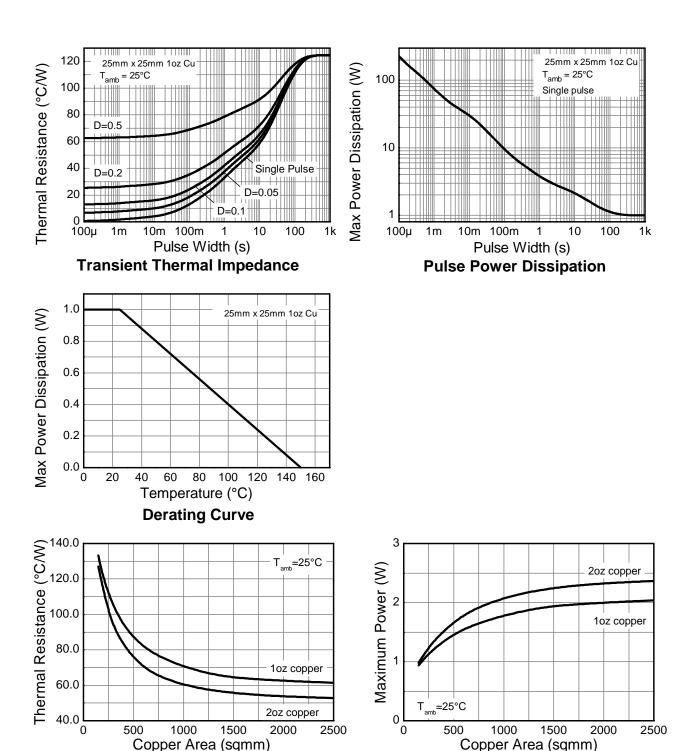
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper. 8. Same as Note 6, except the device is mounted on 50mm x 50mm 1oz copper.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

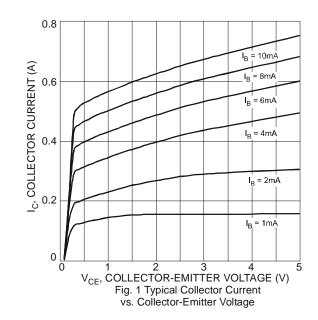


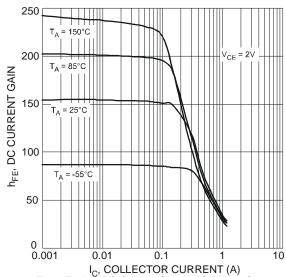


Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

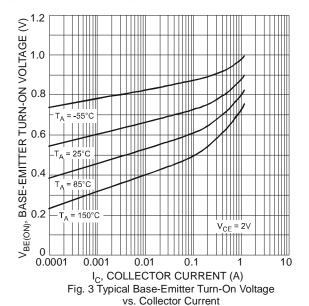
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCX54 BCX55 BCX56	BV _{CBO}	45 60 100	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BCX54 BCX55 BCX56	BV _{CEO}	45 60 80	_	1	V	I _C = 10mA
Emitter-Base Breakdown Voltage		BV_{EBO}	6	_		V	$I_E = 100 \mu A$
Collector Cut-Off Current		I _{CBO}	_	_	0.1 20	μΑ	V _{CB} = 30V V _{CB} = 30V, T _A = +150°C
Emitter Cut-Off Current		I _{EBO}	_	_	20	nA	V _{EB} = 5V
Static Forward Current Transfer Ratio (Note 11)	All versions	h _{FE}	25 40 25 63	_ _ _			I _C = 5mA, V _{CE} = 2V I _C = 150mA, V _{CE} = 2V I _C = 500mA, V _{CE} = 2V
	10 gain grp 16 gain grp		100	_	160 250		$I_C = 150$ mA, $V_{CE} = 2V$ $I_C = 150$ mA, $V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 11)		V _{CE(sat)}	_	_	0.5	V	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 11)		$V_{BE(on)}$	_	_	1.0	٧	I _C = 500mA, V _{CE} = 2V
Transition Frequency		fτ	150	_	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance		Cobo	_	_	25	pF	V _{CB} = 10V, f = 1MHz

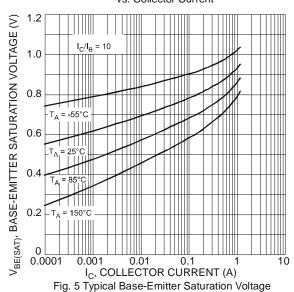
11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%. Note:

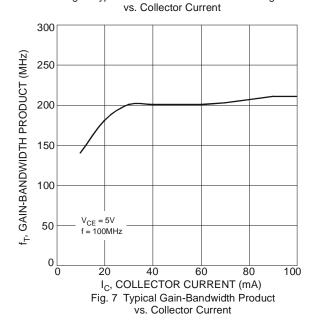












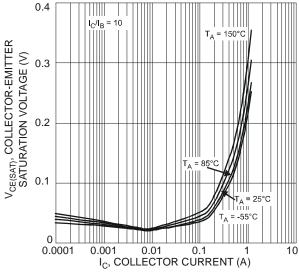


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

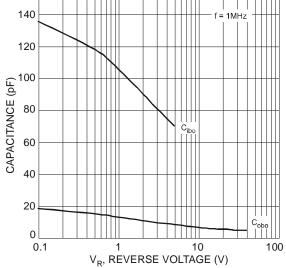
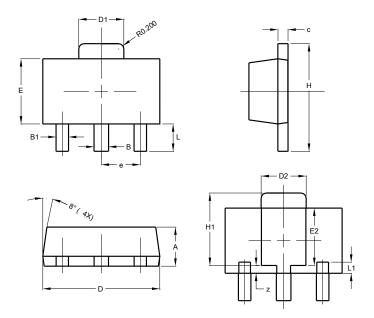


Fig. 6 Typical Capacitance Characteristics



Package Outline Dimensions

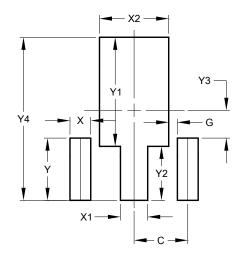
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
C	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
e	-	-	1.50			
Η	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	value
Dilliensions	(in mm)
С	1.500
G	0.244
Χ	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Value



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